

# SPICE Netlist Library (for Multi-Layer Ceramic Capacitors)

Component Solution Division Samsung Electro–Mechanics

Copyright. SAMSUNG ELECTRO-MECHANICS All rights reserved. (Version 5.0)

Contents



1. SPICE Library Guide	3p ~ 10p
2. How to use PSPICE netlist Library	11p ~ 14p
3. How to use LTSPICE netlist Library	15p ~ 17p
4. How to use HSPICE netlist Library	18p ~ 19p
5. How to import netlist file in ANSYS	20p ~ 23p
6. How to import netlist file in ADS	24p ~ 26p
7. How to import netlist file in SIMetrix/SIMPLIS	27p ~ 32p
8. Caution	33p

# 1–1. Type of Models

SAMSUNG SAMSUNG ELECTRO-MECHANICS

We have 4 types of SPICE models for multi-layer ceramic capacitors.



Туре	Elements / Description	DC bias condition	Temperature condition
Interactive Precise Model	*40~60 elements : Insulation Resistor, Capacitance Equivalent	1	file
Precise Model	series resistance, inductance + Piezo peak for <b>each frequency</b> (Closer to the measurement data)	Each download on Web	Each download on Web
Interactive Simple Model	Interactive Simple Model*4 elements (Average value) : Insulation Resistor, Avg Capacitance Equivalent series resistance, Avg Inductance for whole frequency		file
Simple Model			Each download on Web

# 1-2. Simple Models vs Precise Model

SAMSUNG SAMSUNG ELECTRO-MECHANICS



- **Precise model** almost same with the measurement data for each frequency.
- Simple model has two reactance(XC, XL) as average value of measurement data and a constant resistance as impedance value at the self resonant frequency.
- In case of simulation related loss analysis, Precise model might be proper than Simple model.
- Simple model can help obtain simulation result more quickly.

#### Example : CL21A475KBQNNN

\* ESR graph comparison for frequency (Temperature : 25°C, DC bias 0~39V condition)

1) Measurement data

#### 2) Precise model data (S2P/PSPICE Lib)



- ESR data measured by Network Analyzer shows Piezo effect related to DC bias.
- Samsung Precise model has ESR data reflecting Piezo effect. It is similar to measurement data.
- The Piezoelectric Effect occurs in crystals that have no center of symmetry. This lends itself to a net polarization of the crystal.
   Barium titanate MLCCs exhibit a mechanical distortion with applied electric field.





#### Example : CL32B476KPJNNW

\* ESR graph comparison for frequency (Temperature : 25°C, DC bias 10V condition)



2E+2 Z ESR 1E-1 ESR (Ω) **ΔТ (**°C) 2E+1 1E-2 2E+0 1E-3 -2E-1 · 1E+4 1E+5 1E+6 1E+5 1E+4 Frequency (Hz) Frequency (Hz)

2) Loss Measurement data (AC 1A ripple current heating)

1E+6

- ESR data of Precise Model shows 'dielectric loss' and 'Piezo effect' related to DC bias.
- Precise model is better than Simple Model in Loss Analysis.

### 1-4. Interactive model?

As below graph, MLCC of high dielectric constant has DC bias and Temperature dependent characteristics. Our web library is providing each CKT file and S-parameters for specific condition (DC bias / temperature). Especially, Interactive model was included DC bias and temperature dependent characteristics in only one file.



#### [DC bias characteristics]



#### [Temperature characteristics]

- Simple model, Precise model
  - : User should download each files for DC bias/Temperature condition.
  - All inner element was normal passive components.
- Interactive Simple model, Interactive Precise model
  - : One file was reflected DC bias/Temperature dependent characteristics.
  - Inner elements was included some nonlinear components.

SAMSUNG

ELECTRO-MECHANICS

MSUNG

# 1-5. Using Interactive model (Example)

SAMSUNG SAMSUNG ELECTRO-MECHANICS



- Interactive Simple model, Interactive Precise model
  - : One file was reflected DC bias/temperature dependent characteristics.
  - DC bias characteristics are calculated automatically as voltage condition in circuit.
  - Temperature characteristics are calculated automatically by setting simulation condition.

Example : CL21A475KBQNNN [ DC bias sweep (0~40V, 25°C) ]

Measurement data

#### Interactive Precise Model

#### Interactive Simple Model



- One Interactive file was reflected DC bias dependent characteristics for each frequency.

# 1-6. Interactive model characteristics (Freq domain).

SAMSUNG SAMSUNG

#### Example : CL21A475KBQNNN

[Temperature bias sweep (-55°C~ +85°C, 10V DC-bias]

Measurement data

#### ► Interactive Precise Model

#### Interactive Simple Model



- Also, One Interactive file was reflected Temperature dependent characteristics for each frequency.

#### The PSPICE Interactive/static model can be downloaded from SAMSUNG Web site. (http://www.samsungsem.com)

1. Download netlist file. It is recommended to save as. [\*.lib]

#### Simple model Example

#### Precise model Example

* Products : Multilayer Ceramic Capacitor	
* Characteristics :	
* Nominal Capacitance = 4.7uF	
* Capacitance Tolerance = ±10% * TCC = X5B(-55 ~ +85 Cels.)	
* Rated Voltage = 50Vdc	
<pre>* Size = U8U5(unit:inch), 2U12(unit:mm) * Length = 2.00 +/-0.15 mm</pre>	
<pre>* Width = 1.25 +/-0.15 mm_</pre>	
<ul> <li>Thickness = 1.25 +/-0.15 mm</li> <li>Measurement Temperature : 25Cels</li> </ul>	
<ul> <li>DC bias Value = OV</li> </ul>	
*	
* 1 0 1 1 0 2	
* 1 0110 2	
*	
C1 1 3 3.24e-6	
RII 3 1.00e-8 R2 3 4 6.41e-3	
L1 4 2 2.37e-10	
. ENDS UL218475KBUNNN	

\* Products : Multilayer Ceramic Capacitor \* Characteristics : Nominal Capacitance = 4.7uF Nominal Capacitance = 4.7uF Capacitance Tolerance = ±10% TCC = X5R(-55 ~ +85 Cels.) Rated Voltage = 50Vdc Size = 0805(unit:inch), 2012(unit:mm) Length = 2.00 +/-0.15 mm Width = 1.25 +/-0.15 mm Thickness = 1.25 +/-0.15 mm Measurement Temperature : 55Cels. DC bias Value = 10V DC bias Value = 10V \* External Node Assignments : 1 0---||---0 2 SUBCKT CL21A475KBQNNN 1 2 C1 1 3 1.61661e-6 C2 3 4 1.59844e-4 C3 4 5 8.23247e-5 C4 5 6 2.40151e-4 C5 6 7 1.34948e-4 C6 7 8 1.32562e-4 C7 8 9 9.33097e-5 8 9 9.33097e-5 C8 9 10 2.633697e-5 C8 9 10 2.63326e-4 R1 1 3 1.00000e+8 R2 3 4 3.75187e+1 R3 4 5 5.51509 R4 5 6 1.68167 C5 6 1.24049-4 C5 6 7 1.34948e-4 C6 7 8 1.32562e-4 C7 8 9 9.33097e-5 C1 8 9 9.33097e-5 C8 9 10 2.63326e-4 R1 1 3 1.00000e+8 R2 3 4 3.75187e+1 R3 4 5 5.51509 R4 5 6 1.68167 R5 6 7 4.92800e-1 PC 9 6 9.2300e-1 R6 7 8 8.23247e-2 R7 8 9 1.41573e-2 R8 9 10 1.05347e-2 R9 10 11 5.68272e-5 L10 11 12 1.23378e-10 L11 12 13 1.94373e-11 L12 13 14 2.13857e-11 L13 14 15 1.84101e-10 L14 15 16 4.08016=-11 L15 16 4.08016=-11 L15 16 17 5.31596e-13 L16 17 18 3.17535e-10 L17 18 19 3.60562e-10 L18 19 20 2.73866e-10 L19 20 21 8.61761e-12 ENDS C 214A2F2001W1

. ENDS CL21A475KBQNNN

#### Interactive Simple model Example

```
* Products : Multilayer Ceramic Capacitor
* Characteristics :
      Nominal Capacitance = 4.7uF
      Capacitance Tolerance = ±10%
      TCC = X5R(-55 ~ +85 Cels.)
      Rated Voltage = 50Vdc
      Size = 0805(unit:inch), 2012(unit:mm)
      Length = 2.00 +/-0.15 mm
      Width = 1.25 +/-0.15 mm
Thickness = 1.25 +/-0.15 mm
* Applicable condition :
      Frequency : 300Hz ~ 6GHz
      Measurement Temperature : -55 ~ 85Cels.
      DC bias Value = OV ~ 40V
      Small Signal as Network Analyzer
* External Node Assignments :
     0----11---0 2
**$ENCRYPTED_LIB
**$PARTIAL
 SUBCKT CL21A475KBQNNNsimple_DCtemp Port1 Por
$CDNENCSTART_ADV2
17f62b1fb318c25603aeb85644ae98a5720609594b55d
006667ae5346eafe
                      040208b4cec0cae42976dedd
Ode58834cad1b0996 Encrypt7064fe1520c3c5e5a
995a756d20194336
                               373ba3df67ecab9d
6f97a60e025f5b6f448131fa90be07e48e1756be92670
$CDNENCFINISH_ADV2
 .ENDS CL21A475KBQNNNsimple_DCtemp
```

#### Interactive Precise model Example

\* Products : Multilayer Ceramic Capacitor \* Characteristics : Nominal Capacitance = 4.7uF Capacitance Tolerance = ±10% TCC = X5R(-55 ~ +85 Cels.) Rated Voltage = 50Vdc Size = 0005(unit:inch), 2012(unit:mm) Length = 2.00 +/-0.15 mm Width = 1.25 +/-0.15 mm Thickness = 1.25 +/-0.15 mm \* Applicable condition Frequency : 300Hz ~ 6GHz Measurement Temperature : -55 ~ 85Cels. DC bias Value = OV ~ 40V Small Signal as Network Analyzer \* External Node Assignments : \* 1 0---||---0 2 \*\*\$ENCRYPTED\_LIB \*\*\$PARTIAL SUBCKT CL21A475KBQNNN\_DCtemp Port1 Port2 \$CDNENCSTART\_ADV2 7f62b1fb318c25603aeb85644ae98a5720609594b5 f 42281 a1e01 984ca61 ee 9568245776d80530244a17a1 fad8241a74ce51610528c66b7425d2d7cb5155dba8c7 233ac5ee8b6792160737ba26e24ed803314e927de1db 101ca100207e06b791e1e605ba65c033a13f115756de a772424e1573d2be0728fca1fc7d78c7d43c8d969216 a772424e1573d2be0728tca1tc778c7d43c8d96921E 25b1541e69e1a4eb45fa8292b00532b7175tb51657 85bd874f58d535350bc9fde8100391f3bbc12391775 187bda59ad7548bd9461a128b8c1433ac98198tb395 91a26565abcae165bd7756d080b97b1datcaaed1a2 a8e17183049caa1ee6c5004ac0934800a8199e482642 5398306bC0834ce7055094tf56ec08e861f1bb0007 ca14c2tc79bde3b32604bc097b1a017ec5926e73d 8020ed022c151f872604bc095tra30517e580e7954 863ae30b5d0779549cd056ca7656bedc36f176580e7954 863ae30b5d0779549cd056ca765f40fc74b 483ac75848ca69e0dccbd156b4dd7449cb5155dba8c 6d40e3584bd0e62b01d13a3cb46cedc3a48e8e5a252 52bace2dd100c031d8482ea8465c253a8199c482642 e1857111b61cde91075e98231644bb6153182d50b1a 86564671a81bf1f9f0a0879r7bd3e14348b3921535b 32c35bf5014e8d656dbbb1527c0d38d7683ee210daab e2a8cea2588b844d25e353b386b2ae37a2c5f0d065b 7f8357aa23cec549b79fb1ee5fcd6d48cb5155dba8c 94362751000b5b8c9bbc9a7e356f32d1243978b95cb9 cff278d59748dff56dd44ba34321d8cddf19da036203 01e3786b871ba9e3269e3624fbbecd545d6702fee75a 4666aa858079ab80e559cad1c03724964bd1f323ec32 \$CDNENCFINISH\_ADV2

ENDS CL21A475KBQNNN\_DCtemp

11

2. Execute 'PSpice Model Editor'.



3. File  $\rightarrow$  Model Import Wizard.

f:	PSpice Mod	el Editor				
File	Edit Vie	w Model	Plot	Tools	Window	Help
Ľ	New					Ctrl+N
ð	Open					Ctrl+O
	<u>C</u> lose					
	<u>S</u> ave					Ctrl+S
	Save <u>A</u> s					
	Print					Ctrl+P
	Print Pre <u>v</u> ie	PV .				
	Page Set <u>u</u> p.					
	Export to C	anture Part	Libran	1		
	Model Impo	ort Wizard	[Captu	'e]		
2	Encrypt Libr	ary				
	1 D:#pspice	₩CL03C1:	20JA3G	NN_DC	0V	
	<u>2</u> 19A226N	IR7NW2B_	4_Tem	pDC act	ive model_	160913
	3 21 order_2	_netlist160	90711	55_lv_na	aming	
	4 D:₩pspice	#21order_	2_netli	st		
	5 CL21A47	5KBQNNN	Conve	nient m	odel	
	6 GCM21BC	C71A475K	473_12	5		

4. File  $\rightarrow$  Click 'Browse' button and select downloaded file(\*.lib) then press 'Next' button.



5. Configure proper Symbol of Library file and press 'Finish' Buotton. then check message box. \*. OLB file is generated

(1) associate symbol fo	e following : or models without symbol,	or (2) re	eplace existing symbol for models,
Models with symbol Model Name CL21A475KBGNNN	ol Vodels without sy Symbol Name CL21A475KBGNNN Lace Symbol		

~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~
Model Import Wizard : D:\pspice\Cl21A475KBQNNN_DC0V_25deg.symwiz.log
INFO(ORSCH-1132): Log File Error File
STATUS: PSpice Model Import Wizard for "Capture" (16,6,0,d001)
STATUS: INFO: LIB drives flow
INFO: LIB anven now INFO: Input File: D:\msnice\CL 21A475KBQNNN_DC0V_25deg lib
INFO: Output File: D:\pppice\CL21A475KBQNNN_DC0V_25deg,olb
STATUS:
STATUS: Identifying matching symbols automaticallystarted at Monday, October 17, 2016 19:14
INFO: Sumbol "CL214/75KBONNN" alreadu eviste for model "CL214/75KBONNN"
STATUS:
STATUS: Completed identifying matching symbols automaticallyat Monday, October 17, 2016
STATUS:
STATUS: U Error messages, U Warning messages
OK

SAMSUNG

**ELECTRO-MECHANICS** 

NSUNG



6. Execute OrCAD Capture program.



- 7. Place Part(Press "P" key) → 'Add Library' Select generated. \*.OLB file
- Then double click the model name in Part list box and drop-down Model on your schematic sheet.





8. Before simulation Run, OrCAD Capture menu [P Spice]  $\rightarrow$  Edit Simulation Profile.



9. 'Configuration Files' Tab → Select 'Library' in Category → Click 'Browse...' Button
→ Select the downloaded file(\*.lib) and Press
'Add as Global' or 'Add to Design' Button.
then click 'OK' button.





10.(Interactive model case) You can adjust simulation temperature value on 'Options' Tab.

\* Default nominal temperature.

neral Analysis Confi	guration Files Options Data Collec	tion P	robe Wind	ow
ategory: Analog Simulation Sate-level Simulation Output file	Relative accuracy of V's and I's: Best accuracy of voltages: Best accuracy of currents: Best accuracy of charges: Minimum conductance for any branch: DC and bias "blind" iteration limit: DC and bias "blind" iteration limit:	0.001 1.0µ 1.0p 0.01p 1.0E-12 150 20	volts amps coulombs 1/ohm	(.OPTION) (RELTOL) (VNTOL) (ABSTOL) (CHGTOL) (GMIN) (ITL1) (ITL2)
	Transient time point iteration limit:	10	1	(ITL4)
	Default nominal temperature:	27.0	°C	(TNOM)
	Number of Threads (Maximum is 4)	0		(THREADS)
	Advanced Convergence			(ADVCONV)
	Use preordering to reduce matrix fill-in	1.	(F	REORDER)
	AutoConverge MOSEET Options	Advanc	ed Antions	Reset



The LTSPICE Interactive/static model can be downloaded from SAMSUNG Web site. (http://www.samsungsem.com)

1. Download two files in LTSpice Library folder. (Symbol File : .asy / Netlist File : .mod)

- Save symbol file at C:/Program Files/LTC/LTspiceIVII/lib/sym

or C:\Users\Administrator\Documents\LTspiceXVII\lib\sym

- Save encrypted netlist file at C:/Program Files/LTC/LTspiceIVII/lib/sub

or C:\Users\Administrator\Documents\LTspiceXVII\lib\sub

% LTspice version : LTspiceXVII.

X Save both .asy and .mod files at the directory where intended simulation circuit is saved In this case, The model can be used only in the simulation circuits saved at the same directory.





2. Execute LTSPICE program.



- 3. Select component symbol at your schematic.
  - Edit  $\rightarrow$  Component or F2.



C:#Users#Administrator#Documents#LTspiceXV         Open this macromodel's t         CL32B476KPJNNWEncrypt         CL32B476KPJNNWEncrypt         CL32B476KPJNNWEncrypt					
C:\Users\Administrator\Documents\LTspiceXVII\Users\XVII\Users\Classes\VII\Users\Classes\VII\Users\Classes\VII\Users\Classes\VII\Users\Classes\VII\Users\Users\VII\Users\Users\VII\Users\Users\Users\VII\Users\Users\VII\Users	p Directory: C:	₩Users₩Administra	tor₩Documents	₩LTspiceXVII₩lib₩	s) •
E C:₩Users₩Administrator₩Documents₩LTspiceXVII₩lib₩sym₩ [.] CL32B476KPJNNWEncp CL32B476KPJNNWEncŋ			Open this m	nacromodel's test fixtur NNWEncrypt_LT	e
L) CL32B476KPJNNWEncp CL32B476KPJNNWEncp	C·\WI leere\WAda	pinistrator@Documer			herat
	2B476KPJNNWE 2B476KPJNNWE	ncn ncn			



4. Run Simulation as your circuit condition.



- The HSPICE Interactive model can be downloaded from SAMSUNG Web site. (<u>http://www.samsungsem.com</u>)
- 1. Download '\*\_H.lib ' files in HSpice Library folder.
- 2. Open the file as text document, Check the file path and the variable decared as subcircuit.
  - Interactive precise model Example
    - file path name : /proj/hspice/CL32Y106KBJVPJ\_Simple\_Interactive\_H.lib
    - subcircuit variable : CL32B475KCVZNW\_DCtemp

\* CL32B475KCYZNW Multilayer Ceramic Capacitor Interactive Precise Model for HSPICE \* Model Generated by Samsung Electro-Mechanics \* Samsung Spice Model Version 4.0 \* Products : Multilayer Ceramic Capacitor(High Reliability) \* Characteristics : Nominal Capacitance = 4.7uF Capacitance Tolerance = +/-10% TCC = X7R(-55 ~ +125 Cels.) Rated Voltage = 100Vdc Size = 1210(unit:inch), 3225(unit:mm) Length = 3.20 +/-0.30 mm Width = 2.50 +/-0.30 mm Thickness = 2.50 +/-0.30 mm \* Applicable condition : Frequency : 300Hz ~ 6GHz Measurement Temperature : X7R(-55 ~ +125 Cels.) DC bias Value = OV ~ 4OV Small Signal as Network Analyzer \* External Node Assignments : 0---11---0 2 Subcircuit Variable . SUBCKT CL32B475KCVZN₩\_DCtemp Port1 Port2 .PROT doi2@9it#Gwc T-9mjuc-x35ejH>(%d)?=u#/js;B=j;%ep\$v,C'/25B]+):fJ5H#uC(1y)e=u>9%J;X5i#'% UPSVE45\*M;v%9<K:5F(Dz)b5+3:]K=.X5L'Bjs\$**±DCFYDt**c21h)CF'2d6=5!=3)#== 8%,q=/j9x31B;Z**0**\$\$]8**0**DQ jHU/(=h#pH//(=j#GeEuhT35₩3E]ET3V₩\*[Bt;0,j::BE;0,j:\$Bh;0,j:!J=s<<6)6**2**:25!;,9!J2=>+pw±#hP?.pHU

\$\$3;XC\$257J#6Me/vt33u:!%-OX<63[x)z>U)\*[12=i+PC\*#Hp[@2S;K\_Ga!# >|FE\*x# >|FE;h#/RYa1L@T#v1v>H.

SAMSUNG

ELECTRO-MECHANICS

MSUNG



3. Open or Create Simulation Setting file (\*.sp) and set the variables as shown below.



4. Run Simulation.



The netlist file can be downloaded from SAMSUNG Electro-Mechanics Web site. (http://www.samsungsem.com)

2. Execute 'Ansys Electronics Desktop'.



3. After creating a new project, click Insert Circuit Design on the Project menu to execute the circuit.





4. In the Component Libraries window, click the Import Model button on the Symbol tab. Move the scroll bar to select 'Spice'.



5. When the Import Components window appears, select the relevant netlist file and click on the 'Open' button.



-

3

Favorites

SSS\_Multi

XParam

•

6. When Component Import window appears, Check Create Component and click 'OK'.

The corresponding symbol appears at the end of the mouse. Press ESC to release the layout.

Component Import
C Match pin names
Create Components:
🗖 Group similar components
Require consistent parameter values
Select All Deselect All Invert Selected
Name Create Component Symbol Footprint # Pins
CL02A103KP2NNN
J OSE FORICL
OK 취소

SAMSUNG

**ELECTRO-MECHANICS** 

MSUNO

7. In the Components and Symbols folders, Make sure that the parts are as shown. Drag components created from the Components Tree and click to place components.





The netlist file can be downloaded from SAMSUNG Electro-Mechanics Web site. ( http://www.samsungsem.com )

1. Download CKT file.

2. Execute 'Advanced Design System'.



3. Open your own Schematic sheet, Then File > Import.

the ce	ell_1 [test13_lib:cell_1:sche	matic]	(Schematic	):1	
<u>F</u> ile	<u>E</u> dit <u>S</u> elect <u>V</u> iew	Insert	<u>O</u> ptions	Tools	<u>L</u> ayout
	<u>N</u> ew <u>O</u> pen		Ctrl+N Ctrl+O	9	95
	Revert to Saved				
	<u>Save</u> Save <u>A</u> s Save a <u>C</u> opy As Save Design As Te <u>m</u> plate Save A <u>l</u> I		Ctrl+S	· · ·	· · · · · · · · · · · · · · · · · · ·
	<u>P</u> rint Prin <u>t</u> Area		Ctrl+P	 	· · ·
<b>1</b> 22	Import				· · · · · ·
	<u>Export</u> Reports Design Parameters		,		  
x	Exit Advanced Design Sy	stem		- 1	· · · · · ·



4. Click 'Browse' button and select downloaded file [\*.ckt] then press 'OK' button.



5. 'Main library View' shows the imported file in destination library.





#### 6. Drag & drop the imported library to your schematic sheet.



The SIMetrix/SIMPLS Interactive/static model can be downloaded from SAMSUNG Web site. (<u>http://www.samsungsem.com</u>) \*Interactive models can only be used with SIMetrix.

- 1. Download '\_SIM.lib' files in SIMetrix/SIMPLS Library folder.
- 2. Save the library file at the directory where intended simulation circuit is saved in this case or folder of yours.

#### Static model

#### Interactive model

\* External Node Assignments :

\* External Node Assignmen

\* 1 o---||---o 2

.SUBCKT CL31Y106KLKVPN\_Precise\_DC0V\_25degC 1 2

\*#ASSOC symbol=cap\_simple\_subckt category=Samsung\_MLCC\_Automotive simulator=simetrix|simplis C1 1 3 9.39680E-6

C2 3 4 2.53666E-4

C3 4 5 4.72977E-4

C4 5 6 4.95428E-4 C5 6 7 4.74108E-4 



3. Execute SIMetrix-SIMPLIS program.



#### 4. After creating a new SIMetrix Schematic.



5. Drag and drop the downloaded library files or folder into the command shell of SIMetrix





6. When the install or Edit window pop up, Click 'Ok' button.

- files

🥤 Install or Edit	>	<
Install or edit model file		
CL31Y106KLKVPN_Precise_D	COV_25degC_SIM,lib?	
<ul><li>Install</li><li>Edit</li></ul>	Ok Cancel	

When the Select Libraries window pop up, Click the icon. The selected folder move to "Currently Selected Libraries" window. -folder









#### 7. Select [Place] > [From Model Library…] or Ctrl + G

# SIMetrix/SIMPLIS Main Window File Edit View Simulator Place Probe Probe AC/Noise Hierar Image: Ima

8. When the select Device window pop up, Click uploaded file.

🖌 Select Device

* Recently Added Models *	CL31Y106KLKVPN_Precise_DC0V_25degC
* All User Models *	MSCSICJBS1200Vt
* All Models *	MSCSICJBS1700Vt
Diode	MSCSICJBS700Vt
Discrete Time Filters	
Gates	
IGBTs	
LED Drivers	
MOSFETs (Discrete)	
N-channel JFET	
NMOS	
NPN	
P-channel JFET	
PMOS	
PNP	
PSU Controllers	
PSU Drivers	
Samsung_MLCC_Automotive	
Schottky Diodes	
Switching Regulators	
Transim Load	
Transim Source	
Voltage References	
Voltage Regulators	
Zener Diodes	
*** Unknown ***	

#### 9. Test circuit.





#### 1. Applicable condition

Pspice Library files and S-parameter files in Web site are obtain by Network Analyzer using small signal. Proper result might not be obtained if your condition is different from the above one.

#### 2. Terms and conditions regarding SPICE simulation Models and S-parameter files.

- (1) This Simulation Model is provided solely for reference purposes. For the characteristics of products, You have to refer to the Specifications.
- (2) In no event shall SAMSUNG Electro-Mechanics be liable for any loss or damage arising, Directly or indirectly, from, in connection with your reliance on any information contained in the Simulation Model, including, But not limited to any loss or damages arising from any inaccuracies, omissions or errors in connection with such information.
  (3) SAMSUNG Electro-Mechanics does not make any warranty, Express or implied, including but not limited to the correctness, implied warranties of merchantability and fitness for a particular purpose with respect to this Simulation Model. Any information contained in the Simulation Model is subject to modifications or changes by SAMSUNG Electro-Mechanics without any prior notice.



Copyright. SAMSUNG ELECTRO-MECHANICS All rights reserved. (Version 5.0)